

July 1999 Revised June 2003

74VCX86

Low Voltage Quad 2-Input Exclusive-OR Gate with 3.6V Tolerant Inputs and Outputs

General Description

The VCX86 contains four 2-input exclusive OR gates. This product is designed for low voltage (1.2V to 3.6V) V_{CC} applications with I/O compatibility up to 3.6V

The 74VCX86 is fabricated with an advanced CMOS technology to achieve high-speed operation while maintaining low CMOS power dissipation.

Features

- 1.2V to 3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- ton

3.0 ns max for 3.0V to 3.6V V_{CC}

- Power-off high impedance inputs and outputs
- Static Drive (I_{OH}/I_{OL}) ±24 mA @ 3.0V V_{CC}
- Uses patented noise/EMI reduction circuitry
- Latchup performance exceeds 300 mA
- ESD performance:

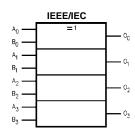
Human body model > 2000V Machine model > 250V

Ordering Code:

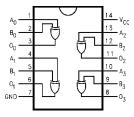
Order Number	Package Number	Package Description
74VCX86M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
74VCX86MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A _n , B _n	Inputs
O _n	Outputs

Absolute Maximum Ratings(Note 1)

-0.5V to +4.6V Supply Voltage (V_{CC}) DC Input Voltage (V_I) -0.5V to +4.6V Output Voltage (V_O) HIGH or LOW State (Note 2) -0.5V to V_{CC} +0.5V $V_{CC} = 0V$ -0.5V to +4.6VDC Input Diode Current (I_{IK}) $V_I < 0V$ -50 mA DC Output Diode Current (I_{OK}) $V_O < 0V$ -50 mA $V_{O} > V_{CC}$ +50 mA DC Output Source/Sink Current (I_{OH}/I_{OL}) ±50 mA

Recommended Operating Conditions (Note 3)

Power Supply	
Operating	1.2V to 3.6V
Input Voltage	-0.3V to $+3.6V$
Output Voltage (V _O)	
HIGH or LOW State	0V to V_{CC}
Output Current in I _{OH} /I _{OL}	
$V_{CC} = 3.0V \text{ to } 3.6V$	±24 mA
$V_{CC} = 2.3V \text{ to } 2.7V$	±18 mA
$V_{CC} = 1.65V \text{ to } 2.3V$	±6 mA
$V_{CC} = 1.4V \text{ to } 1.6V$	±2 mA
$V_{CC} = 1.2V$	±100 μA
Free Air Operating Temperature (T _A)	-40°C to +85°C

Minimum Input Edge Rate (Δt/ΔV)

 $V_{IN} = 0.8V$ to 2.0V, $V_{CC} = 3.0V$ 10 ns/V

Note 1: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: IO Absolute Maximum Rating must be observed.

Note 3: Floating or unused inputs must be held HIGH or LOW.

DC Electrical Characteristics

Storage Temperature Range (T_{STG})

Symbol	Parameter	Conditions	V _{CC} (V)	Min	Max	Units
V _{IH}	HIGH Level Input Voltage		2.7 - 3.6	2.0		
			2.3 - 2.7	1.6		
			1.65 - 2.3	0.65 × V _{CC}		V
			1.4 - 1.6	0.65 × V _{CC}		
			1.2	0.65 × V _{CC}		
V _{IL}	LOW Level Input Voltage		2.7 - 3.6		0.8	
			2.3 - 2.7		0.7	
			1.65 - 2.3		$0.35 \times V_{CC}$	V
			1.4 - 1.6		$0.35 \times V_{\text{CC}}$	
			1.2			
V _{OH}	HIGH Level Output Voltage	$I_{OH} = -100 \mu A$	2.7 - 3.6	V _{CC} - 0.2		
		$I_{OH} = -12 \text{ mA}$	2.7	2.2		
		$I_{OH} = -18 \text{ mA}$	3.0	2.4		
		$I_{OH} = -24 \text{ mA}$	3.0	2.2		
		$I_{OH} = -100 \mu A$	2.3 - 2.7	V _{CC} - 0.2		
		$I_{OH} = -6 \text{ mA}$	2.3	2.0		
		$I_{OH} = -12 \text{ mA}$	2.3	1.8		V
		$I_{OH} = -18 \text{ mA}$	2.3	1.7		
		$I_{OH} = -100 \mu A$	1.65 - 2.3	V _{CC} - 0.2		
		$I_{OH} = -6 \text{ mA}$	1.65	1.25		
		$I_{OH} = -100 \mu A$	1.4 - 1.6	V _{CC} - 0.2		
		$I_{OH} = -2 \text{ mA}$	1.4	1.05		
		$I_{OH} = -100 \ \mu A$	1.2	V _{CC} - 0.2		

±100 mA

-65°C to +150°C

DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V _{CC}	Min	Max	Units
V _{OL}	LOW Level Output Voltage	$I_{OL} = 100 \mu A$	2.7 - 3.6		0.2	
		I _{OL} = 12 mA	2.7		0.4	
		I _{OL} = 18 mA	3.0		0.4	
		I _{OL} = 24 mA	3.0		0.55	
		$I_{OL} = 100 \mu A$	2.3 - 2.7		0.2	
		I _{OL} = 12 mA	2.3		0.4	V
		I _{OL} = 18 mA	2.3		0.6	V
		I _{OL} = 100 μA	1.65 - 2.3		0.2	
		I _{OL} = 6 mA	1.65		0.3	
		I _{OL} = 100 μA	1.4 - 1.6		0.2	
		I _{OL} = 2 mA	1.4		0.35	
		I _{OL} = 100 μA	1.2		0.05	
I	Input Leakage Current	0 ≤ V _I ≤ 3.6V	1.2 - 3.6		±5.0	μΑ
I _{OFF}	Power-OFF Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	μΑ
I _{CC}	Quiescent Supply Current	V _I = V _{CC} or GND	1.2 - 3.6		20	^
		$V_{CC} \leq (V_I)$	1.2 - 3.6		±20	μА
ΔI_{CC}	Increase in I _{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.7 - 3.6		750	μΑ

AC Electrical Characteristics (Note 4)

Symbol	Parameter	Conditions	V _{CC}	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		Units	Figure
			(V)	Min	Max	Omics	Number
t _{PHL}	Propagation Delay	$C_L = 30 \text{ pF}, R_L = 500\Omega$	3.3 ± 0.3	0.6	3.0		
t _{PLH}			2.5 ± 0.2	0.8	3.9		Figures 1, 2
			1.8 ± 0.15	1.0	7.8	ns	.,_
		$C_L = 15 \text{ pF}, R_L = 2k\Omega$	1.5 ± 0.1	1.0	15.6		Figures
			1.2	1.5	39		3, 4
toshl	Output to Output Skew	$C_L = 30 \text{ pF}, R_L = 500\Omega$	3.3 ± 0.3		0.5		
toslh	(Note 5)		2.5 ± 0.2		0.5		
			1.8 ± 0.15		0.75	ns	
		$C_L = 15 \text{ pF}, R_L = 2k\Omega$	1.5 ± 0.1		1.5		
			1.2		1.5		

Note 4: For $C_L = 50_P F$, add approximately 300 ps to the AC maximum specification.

Note 5: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

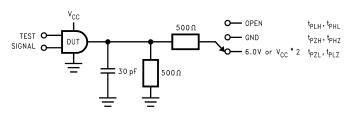
Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V _{CC}	T _A = +25°C	Units
V _{OLP}	Quiet Output Dynamic Peak V _{OL}	$C_L = 30 \text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0V$	1.8	0.25	
			2.5	0.6	V
			3.3	0.8	
V _{OLV}	Quiet Output Dynamic Valley V _{OL}	$C_L = 30 \text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0V$	1.8	-0.25	
			2.5	-0.6	V
			3.3	-0.8	
V _{OHV}	Quiet Output Dynamic Valley V _{OH}	$C_L = 30 \text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0V$	1.8	1.5	
			2.5	1.9	V
			3.3	2.2	

Capacitance

Symbol	Parameter	Conditions	$T_A = +25^{\circ}C$	Units
- Cymbol	i didiliotoi	Conditions	Typical	· Oillio
C _{IN}	Input Capacitance	$V_{CC} = 1.8, 2.5 \text{V or } 3.3 \text{V, } V_{I} = 0 \text{V or } V_{CC}$	6	pF
C _{OUT}	Output Capacitance	$V_I = 0V \text{ or } V_{CC}, V_{CC} = 1.8V, 2.5V \text{ or } 3.3V$	7	pF
C _{PD}	Power Dissipation Capacitance	$V_I = 0V \text{ or } V_{CC}, f = 10 \text{ MHz}, V_{CC} = 1.8V, 2.5V \text{ or } 3.3V$	20	pF

AC Loading and Waveforms (V $_{CC}$ 3.3V \pm 0.3V to 1.8V \pm 0.15V)



TEST	SWITCH
t _{PLH} , t _{PHL}	Open
	TOURE 4 AC Tout Cinemit

FIGURE 1. AC Test Circuit

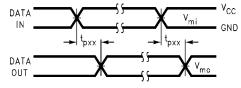
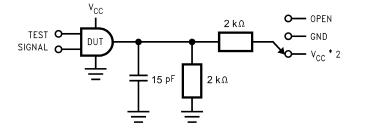


FIGURE 2. Waveform for Inverting and Non-Inverting Functions

Symbol	V _{CC}				
Cymbol	$3.3V \pm 0.3V$	2.5V ± 0.2V	1.8V ± 0.15V		
V _{mi}	1.5V	V _{CC} /2	V _{CC} /2		
V _{mo}	1.5V	V _{CC} /2	V _{CC} /2		

AC Loading and Waveforms (V $_{CC}$ 1.5V \pm 0.1V to 1.2V)



t_{PLH}, t_{PHL}
t_{PZH} , t_{PHZ}
t_{PZL}, t_{PLZ}

TEST	SWITCH
t_{PLH},t_{PHL}	Open
t_{PZL},t_{PLZ}	V_{CC} x 2 at V_{CC} = 1.5 ± 0.1V
t_{PZH}, t_{PHZ}	GND

FIGURE 3. AC Test Circuit

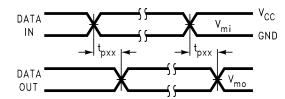
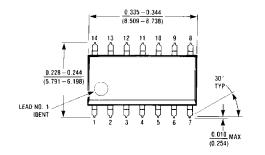
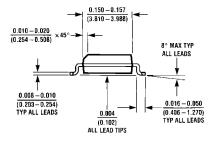


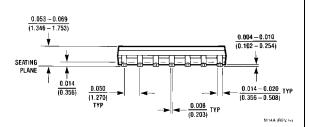
FIGURE 4. Waveform for Inverting and Non-Inverting Functions

Symbol	v _{cc}
	$1.5V \pm 0.1V$
V _{mi}	V _{CC} /2
V_{mo}	V _{CC} /2

Physical Dimensions inches (millimeters) unless otherwise noted

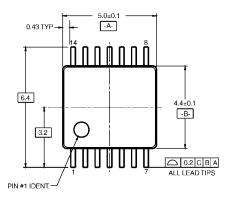


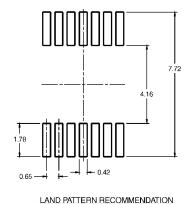


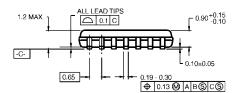


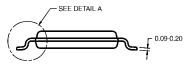
14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Package Number M14A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)





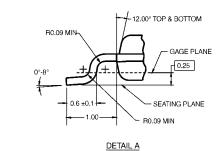




NOTES:

- A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.
- D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC14RevC3



14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide Package Number MTC14

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